



# PMEG6045ETP

High-temperature 60 V, 4.5 A Schottky barrier rectifier

4 March 2013

Product data sheet

## 1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD128 small and flat lead Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- Average forward current:  $I_{F(AV)} \leq 4.5$  A
- Reverse voltage:  $V_R \leq 60$  V
- Low forward voltage
- High power capability due to clip-bonding technology
- Small and flat lead SMD plastic package
- AEC-Q101 qualified
- High temperature  $T_J \leq 175$  °C

## 3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption application

## 4. Quick reference data

Table 1. Quick reference data

| Symbol      | Parameter               | Conditions  | Min | Typ | Max | Unit    |
|-------------|-------------------------|---|-----|-----|-----|---------|
| $I_{F(AV)}$ | average forward current | $\delta = 0.5$ ; $f = 20$ kHz; $T_{sp} \leq 155$ °C; square wave                  | -   | -   | 4.5 | A       |
| $V_R$       | reverse voltage         | $T_J = 25$ °C   | -   | -   | 60  | V       |
| $V_F$       | forward voltage         | $I_F = 4.5$ A; $t_p \leq 300$ $\mu$ s; $\delta \leq 0.02$ ; $T_J = 25$ °C; pulsed | -   | 460 | 530 | mV      |
| $I_R$       | reverse current         | $T_J = 25$ °C; $V_R = 60$ V; pulsed   | -   | 115 | 400 | $\mu$ A |





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## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline  | Graphic symbol  |
|-----|--------|-------------|---|---|
| 1   | K      | cathode[1]  | <br>SOD128 | <br>sym001 |
| 2   | A      | anode       |   |   |

[1] The marking bar indicates the cathode.

## 6. Ordering information

Table 3. Ordering information

| Type number | Package |  |         |
|-------------|---------|--|---------|
|             | Name    | Description                              | Version |
| PMEG6045ETP | SOD128  | plastic surface-mounted package; 2 leads | SOD128  |

## 7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMEG6045ETP | DC           |

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol      | Parameter                           | Conditions   |     | Min | Max  | Unit               |
|-------------|-------------------------------------|--|-----|-----|------|--------------------|
| $V_R$       | reverse voltage                     | $T_j = 25\text{ }^{\circ}\text{C}$   |     | -   | 60   | V                  |
| $I_F$       | forward current                     | $T_{sp} = 150\text{ }^{\circ}\text{C}$   |     | -   | 6.3  | A                  |
| $I_{F(AV)}$ | average forward current             | $\delta = 0.5$ ; $f = 20\text{ kHz}$ ; $T_{amb} \leq 35\text{ }^{\circ}\text{C}$ ; square wave | [1] | -   | 4.5  | A                  |
|             |                                     | $\delta = 0.5$ ; $f = 20\text{ kHz}$ ; $T_{sp} \leq 155\text{ }^{\circ}\text{C}$ ; square wave |     | -   | 4.5  | A                  |
| $I_{FSM}$   | non-repetitive peak forward current | $t_p = 8\text{ ms}$ ; $T_{j(init)} = 25\text{ }^{\circ}\text{C}$ ; square wave                 |     | -   | 70   | A                  |
| $P_{tot}$   | total power dissipation             | $T_{amb} \leq 25\text{ }^{\circ}\text{C}$  | [2] | -   | 750  | mW                 |
|             |                                     |  | [3] | -   | 1250 | mW                 |
|             |                                     |  | [1] | -   | 2500 | mW                 |
| $T_j$       | junction temperature                |  |     | -   | 175  | $^{\circ}\text{C}$ |

| Symbol           | Parameter           | Conditions |  | Min | Max | Unit |
|------------------|---------------------|------------|--|-----|-----|------|
| T <sub>amb</sub> | ambient temperature |            |  | -55 | 175 | °C   |
| T <sub>stg</sub> | storage temperature |            |  | -65 | 175 | °C   |

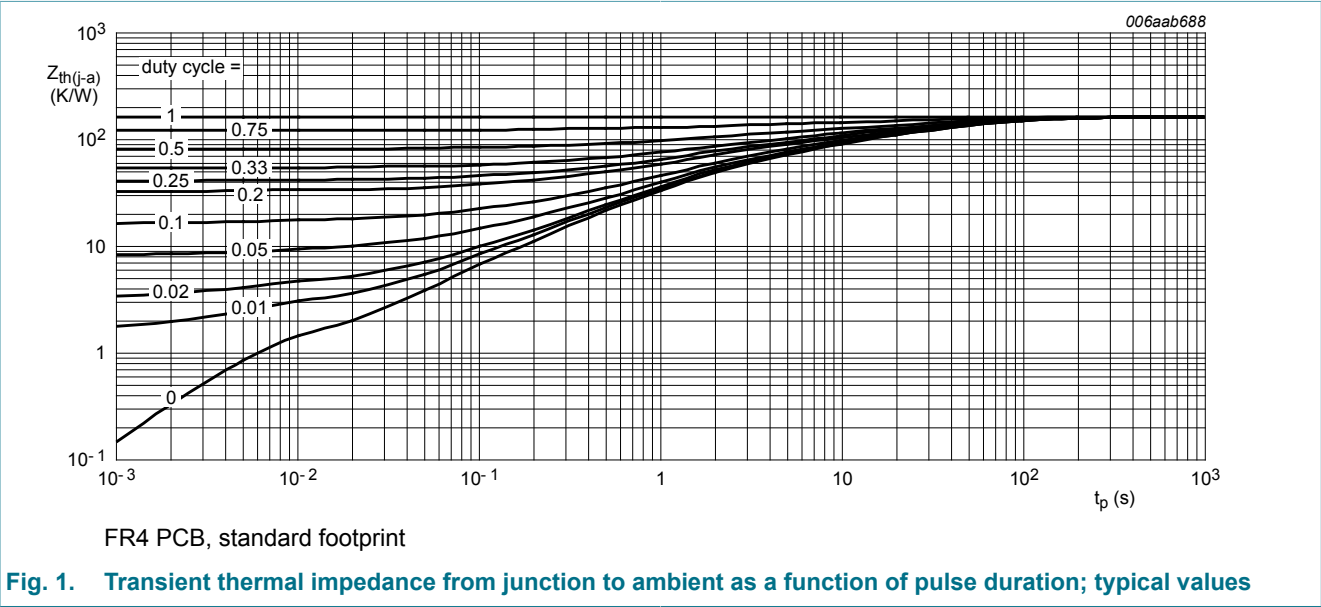
- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

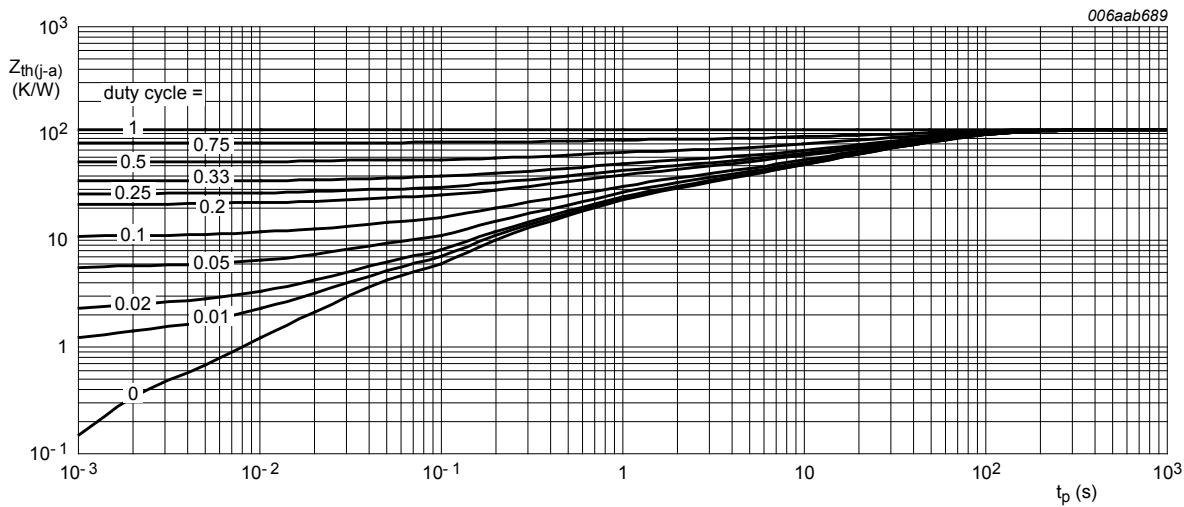
9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol                | Parameter  | Conditions  |        | Min | Typ | Max | Unit |
|-----------------------|--|-------------|--------|-----|-----|-----|------|
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient      | in free air | [1][2] | -   | -   | 200 | K/W  |
|                       |  |             | [1][3] | -   | -   | 120 | K/W  |
|                       |  |             | [1][4] | -   | -   | 60  | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             | [5]    | -   | -   | 12  | K/W  |

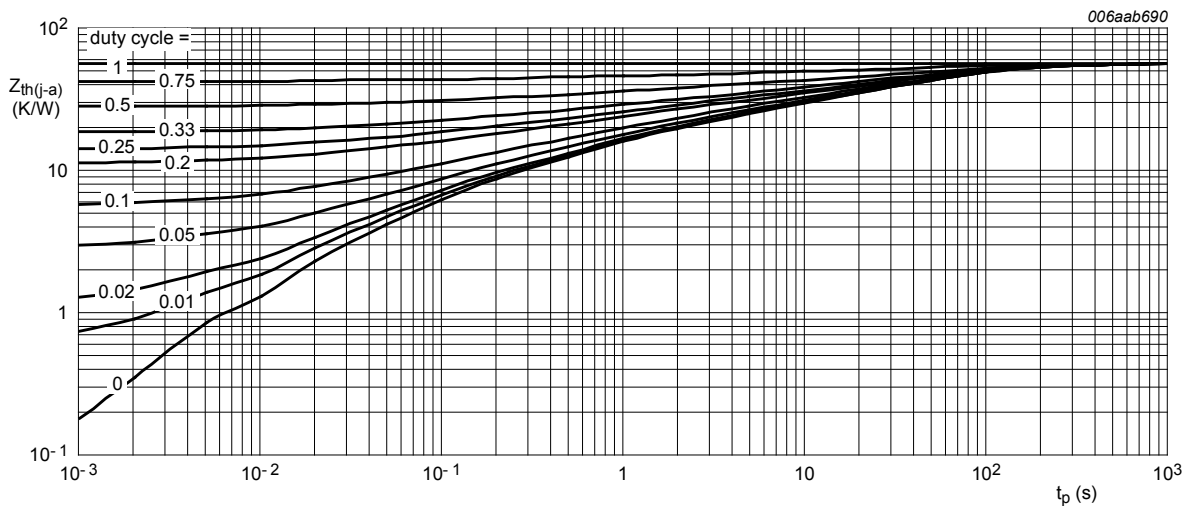
- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- [4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [5] Soldering point of cathode tab.





FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

| Symbol         | Parameter       | Conditions  | Min | Typ | Max | Unit |
|----------------|-----------------|---|-----|-----|-----|------|
| V <sub>F</sub> | forward voltage | I <sub>F</sub> = 0.1 A; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02 ;<br>T <sub>j</sub> = 25 °C; pulsed | -   | 275 | 310 | mV   |
|                |                 | I <sub>F</sub> = 0.5 A; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02 ;<br>T <sub>j</sub> = 25 °C; pulsed | -   | 325 | -   | mV   |
|                |                 | I <sub>F</sub> = 1 A; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02 ;<br>T <sub>j</sub> = 25 °C; pulsed   | -   | 355 | 400 | mV   |

## High-temperature 60 V, 4.5 A Schottky barrier rectifier

| Symbol    | Parameter                     | Conditions   |  | Min | Typ | Max | Unit          |
|-----------|-------------------------------|--|--|-----|-----|-----|---------------|
|           |                               | $I_F = 1.5 \text{ A}; t_p \leq 300 \mu\text{s}; \delta \leq 0.02$ ;<br>$T_j = 25 \text{ }^\circ\text{C}$ ; pulsed    |  | -   | 375 | -   | mV            |
|           |                               | $I_F = 2 \text{ A}; t_p \leq 300 \mu\text{s}; \delta \leq 0.02$ ;<br>$T_j = 25 \text{ }^\circ\text{C}$ ; pulsed      |  | -   | 390 | 440 | mV            |
|           |                               | $I_F = 3 \text{ A}; t_p \leq 300 \mu\text{s}; \delta \leq 0.02$ ;<br>$T_j = 25 \text{ }^\circ\text{C}$ ; pulsed      |  | -   | 420 | 475 | mV            |
|           |                               | $I_F = 4 \text{ A}; t_p \leq 300 \mu\text{s}; \delta \leq 0.02$ ;<br>$T_j = 25 \text{ }^\circ\text{C}$ ; pulsed      |  | -   | 450 | 510 | mV            |
|           |                               | $I_F = 4.5 \text{ A}; t_p \leq 300 \mu\text{s}; \delta \leq 0.02$ ;<br>$T_j = 25 \text{ }^\circ\text{C}$ ; pulsed    |  | -   | 460 | 530 | mV            |
| $I_R$     | reverse current               | $V_R = 5 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ ; pulsed  |  | -   | 7   | 20  | $\mu\text{A}$ |
|           |                               | $V_R = 10 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ ; pulsed   |  | -   | 9   | 40  | $\mu\text{A}$ |
|           |                               | $V_R = 30 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ ; pulsed   |  | -   | 20  | 80  | $\mu\text{A}$ |
|           |                               | $V_R = 60 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ ; pulsed   |  | -   | 115 | 400 | $\mu\text{A}$ |
|           |                               | $V_R = 10 \text{ V}; T_j = 125 \text{ }^\circ\text{C}$ ; pulsed  |  | -   | 9   | -   | mA            |
|           |                               | $V_R = 60 \text{ V}; T_j = 125 \text{ }^\circ\text{C}$ ; pulsed  |  | -   | 70  | 300 | mA            |
| $C_d$     | diode capacitance             | $V_R = 1 \text{ V}; f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C}$  |  | -   | 575 | -   | pF            |
|           |                               | $V_R = 10 \text{ V}; f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C}$   |  | -   | 200 | -   | pF            |
| $t_{rr}$  | reverse recovery time         | $I_F = 0.5 \text{ A}; I_R = 0.5 \text{ A}; I_{R(\text{meas})} = 0.1 \text{ A};$<br>$T_j = 25 \text{ }^\circ\text{C}$ |  | -   | 20  | -   | ns            |
| $V_{FRM}$ | peak forward recovery voltage | $I_F = 1 \text{ A}; dI_F/dt = 40 \text{ A}/\mu\text{s}; T_j = 25 \text{ }^\circ\text{C}$                             |  | -   | 385 | -   | mV            |

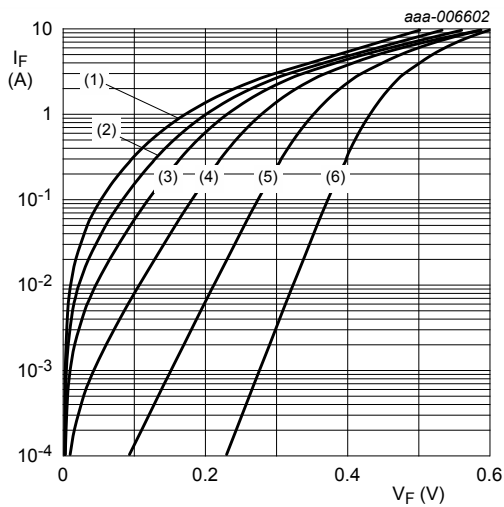


Fig. 4. Forward current as a function of forward voltage; typical values

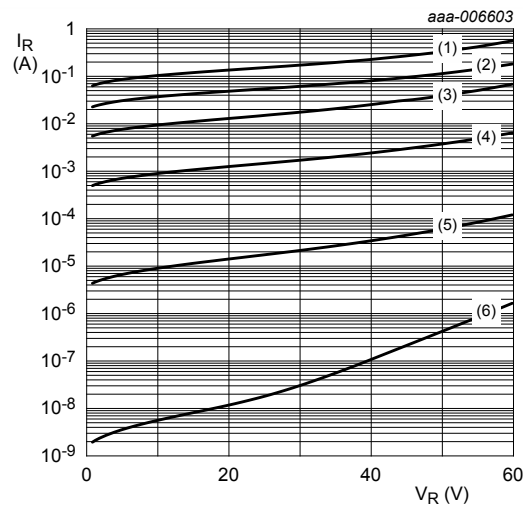


Fig. 5. Reverse current as a function of reverse voltage; typical values

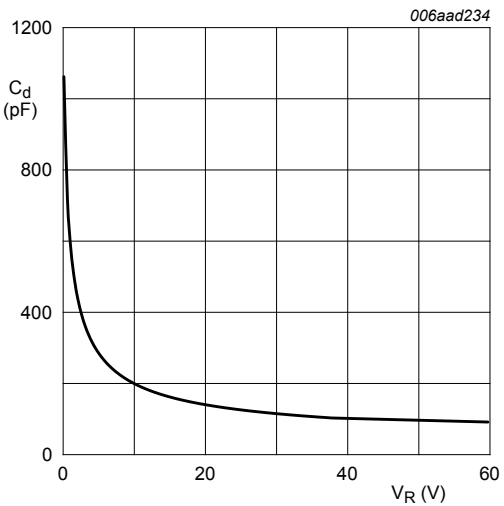


Fig. 6. Diode capacitance as a function of reverse voltage; typical values

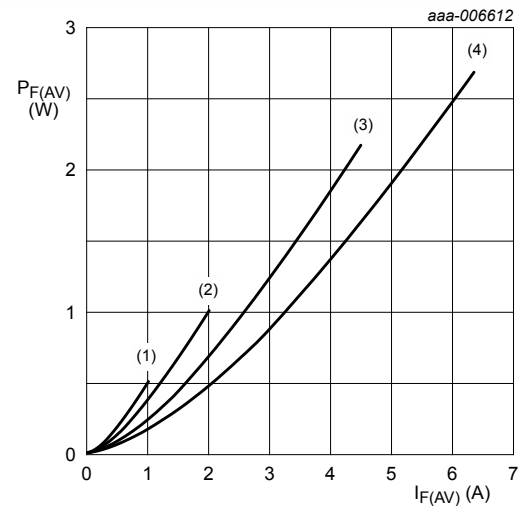


Fig. 7. Average forward power dissipation as a function of average forward current; typical values

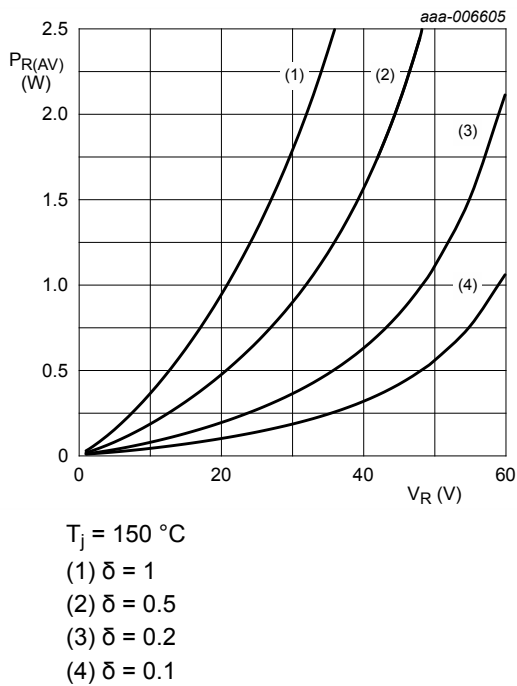


Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values

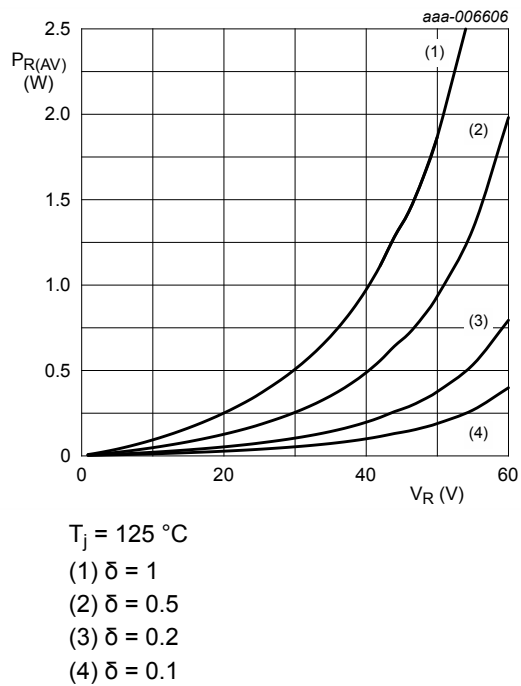


Fig. 9. Average reverse power dissipation as a function of reverse voltage; typical values

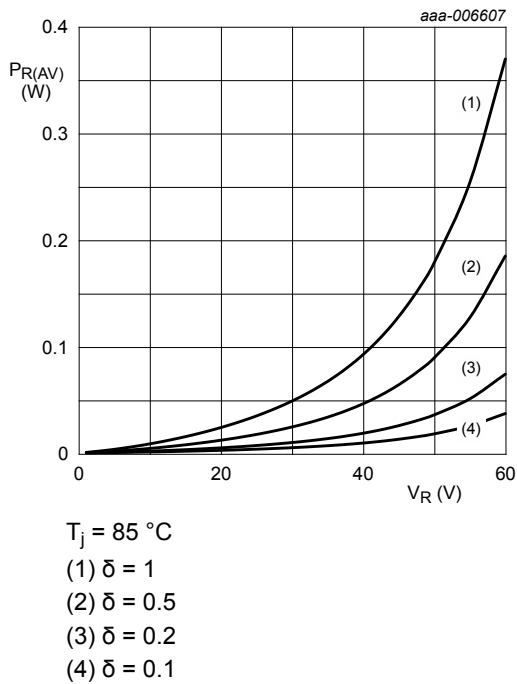


Fig. 10. Average reverse power dissipation as a function of reverse voltage; typical values

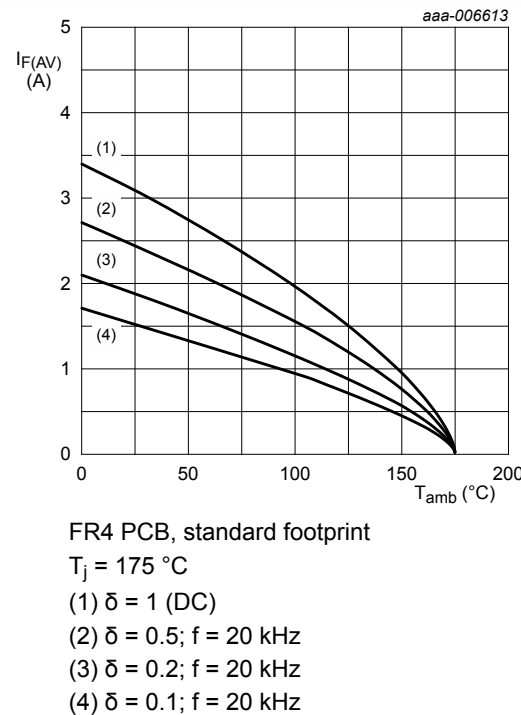
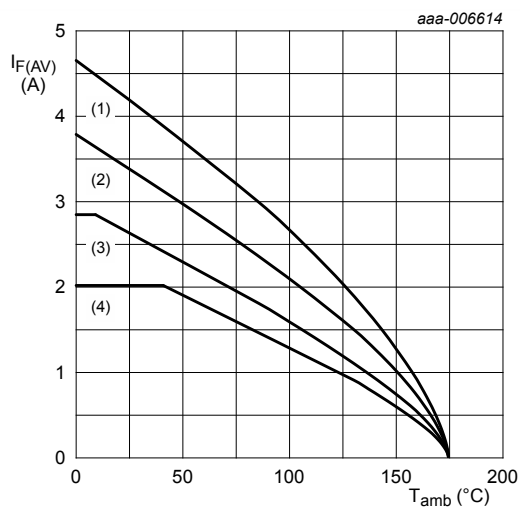
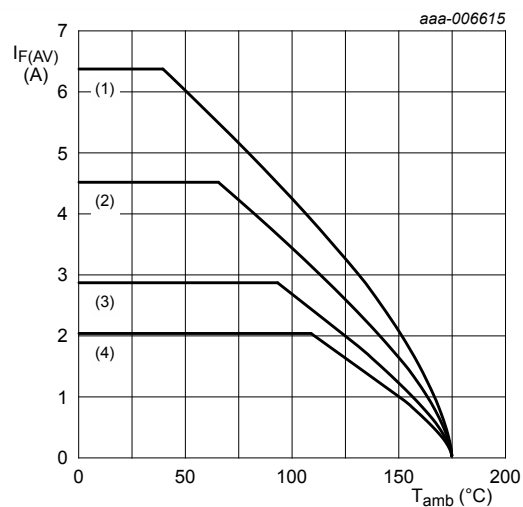


Fig. 11. Average forward current as a function of ambient temperature; typical values



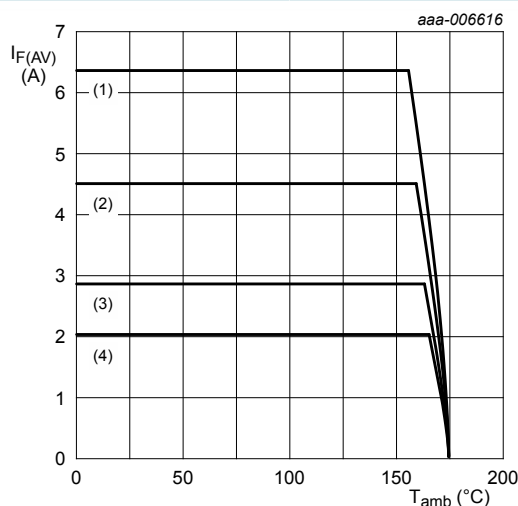
FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>  
 $T_j = 175\text{ °C}$   
 (1)  $\delta = 1$  (DC)  
 (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$   
 (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$   
 (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig. 12. Average forward current as a function of ambient temperature; typical values**



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint  
 $T_j = 175\text{ °C}$   
 (1)  $\delta = 1$  (DC)  
 (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$   
 (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$   
 (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig. 13. Average forward current as a function of ambient temperature; typical values**



$T_j = 175\text{ °C}$   
 (1)  $\delta = 1$  (DC)  
 (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$   
 (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$   
 (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig. 14. Average forward current as a function of solder point temperature; typical values**



## 11. Test information

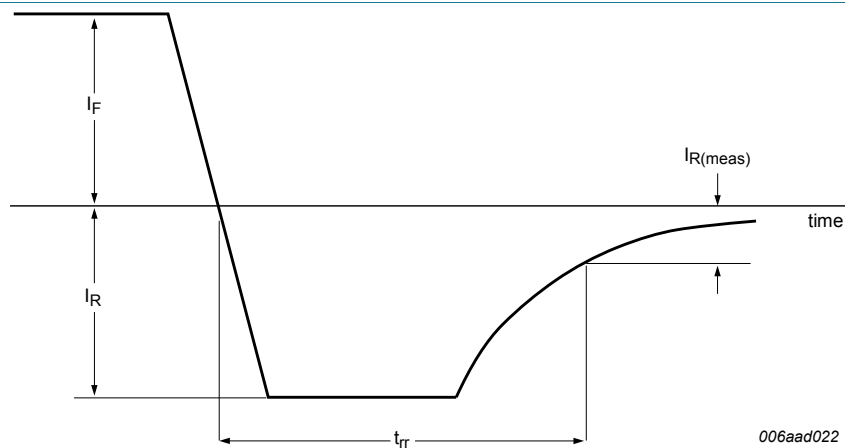


Fig. 15. Reverse recovery definition

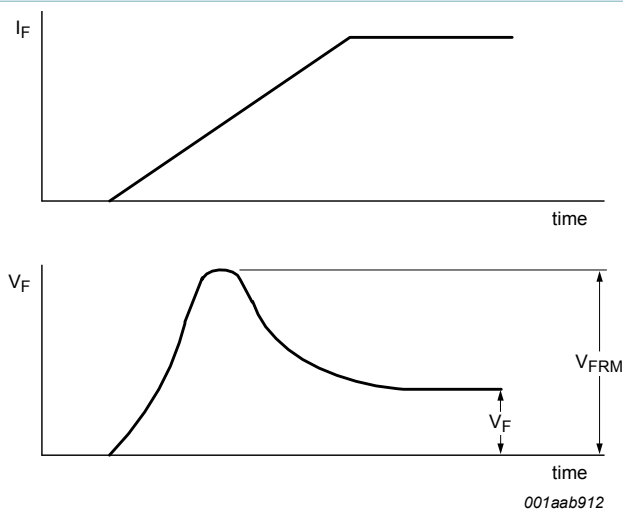


Fig. 16. Forward recovery definition

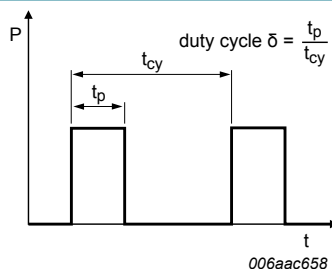


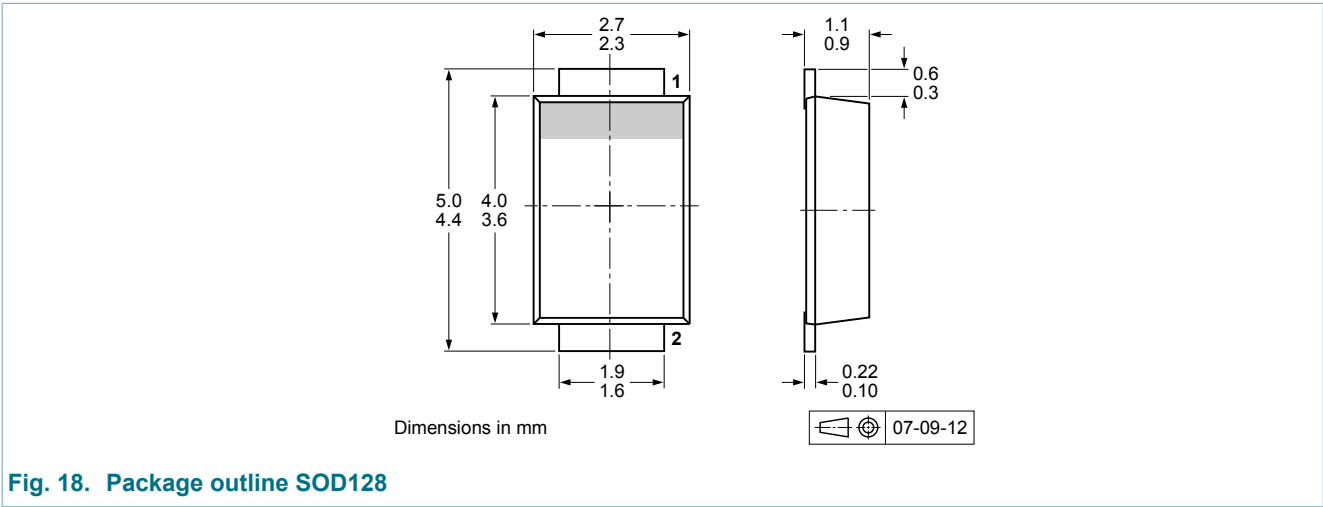
Fig. 17. Duty cycle definition

The current ratings for the typical waveforms are calculated according to the equations:  
 $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

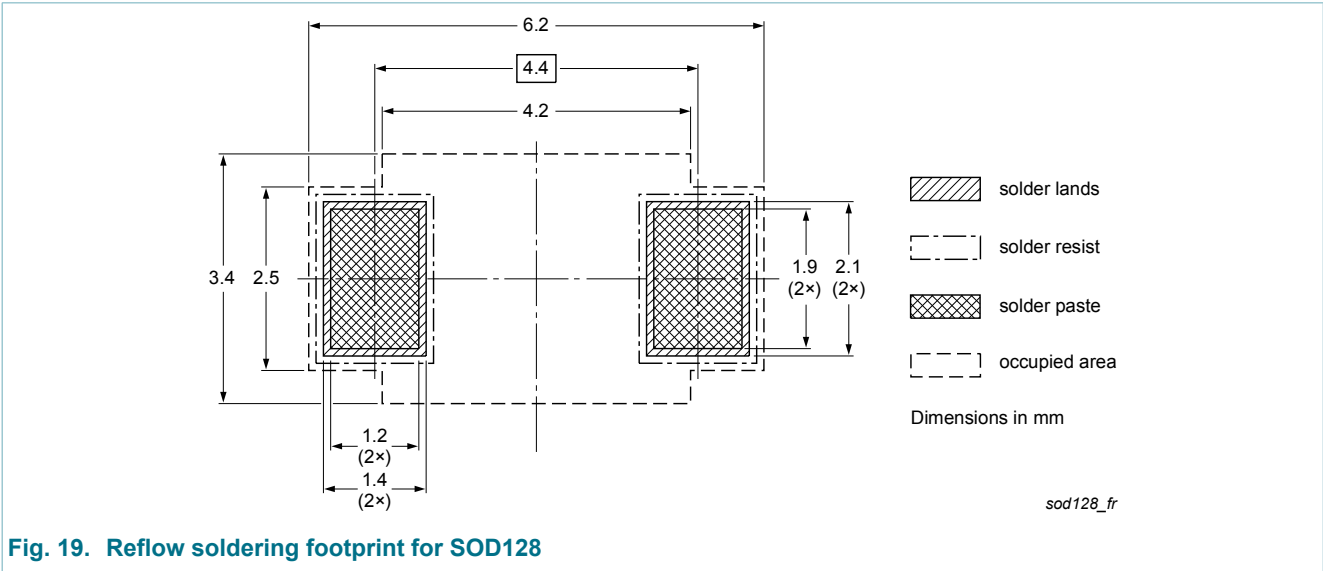
11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



## 14. Revision history

Table 8. Revision history

| Data sheet ID   | Release date | Data sheet status  | Change notice | Supersedes |
|-----------------|--------------|--------------------|---------------|------------|
| PMEG6045ETP v.1 | 20130304     | Product data sheet | -             | -          |

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### 15.1 Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 4 March 2013

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